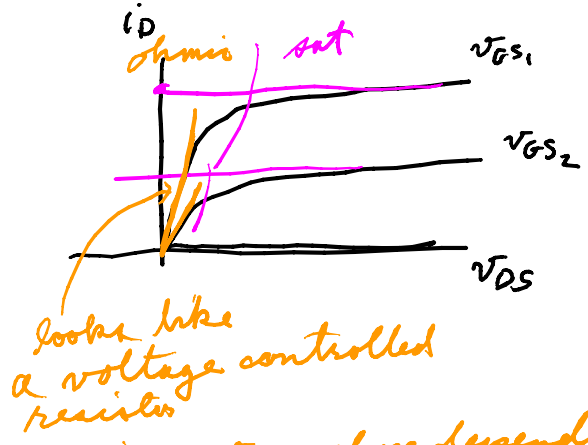
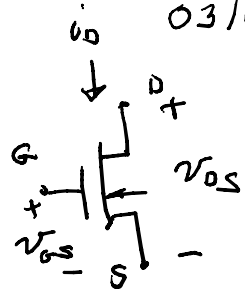


EE 303
03/07/07

NMOS



looks like a voltage controlled resistor

i_D vs V_{DS} slope depends on V_{GS}

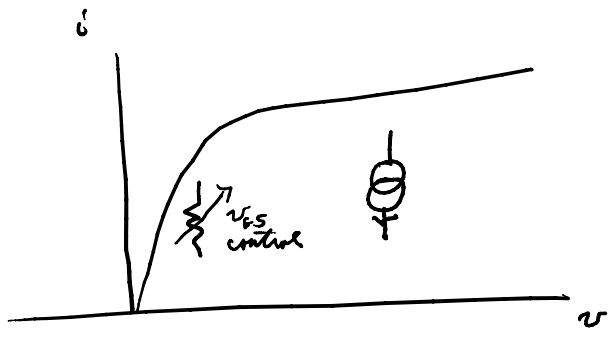
in ohmic region

$$i_D = \frac{K_P W}{2 L} (2(V_{GS} - V_{TO})V_{DS} - V_{DS}^2) (1 + \lambda V_{DS})$$

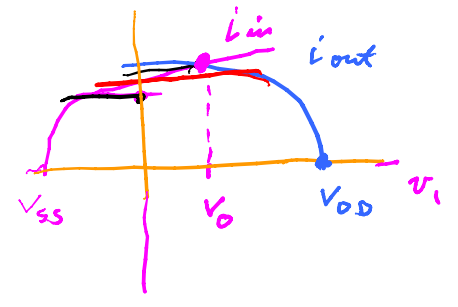
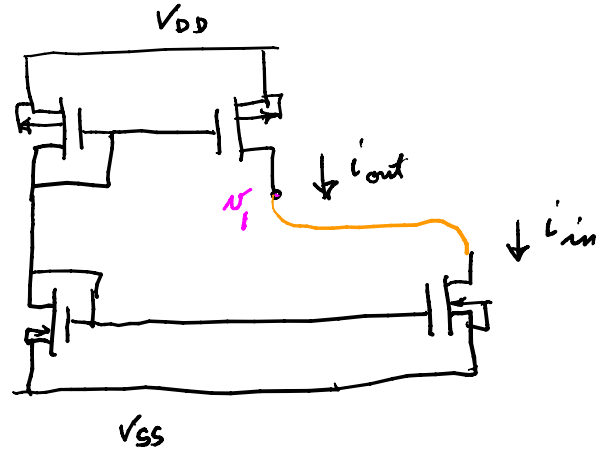
for small V_{DS} , i.e. $V_{DS}^2 \leq \epsilon$, small

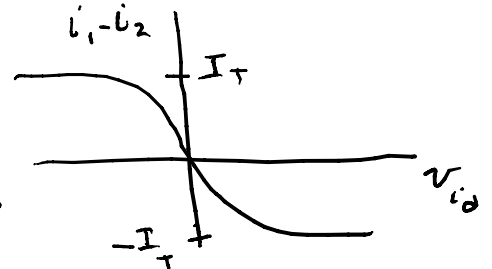
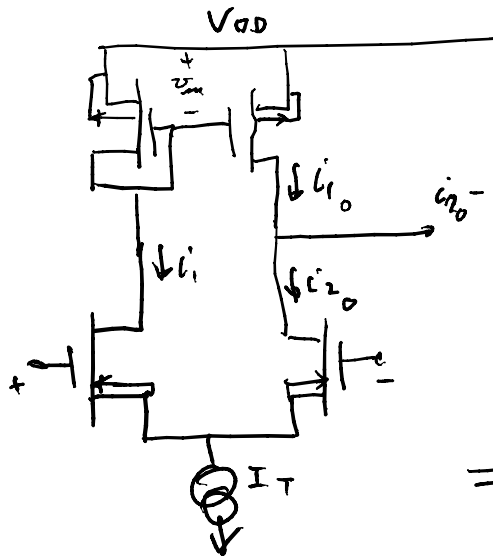
gives slope for "current source"

$$i_D \approx \left\{ \frac{K_P W}{L} (V_{GS} - V_{TO}) \right\} V_{DS} = \underbrace{G(V_{GS})}_{\text{a resistor}} \cdot V_{DS}$$

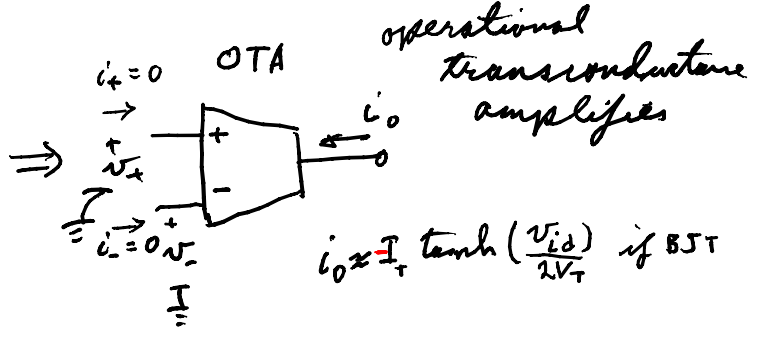


Putting two current sources





$$i_{n1} - i_{n2} = i_o$$

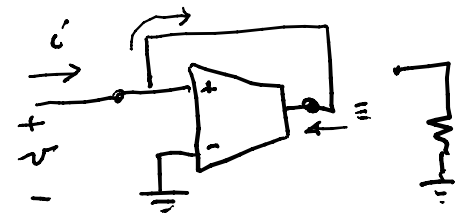


for small signals
 $i_o = -g_m v_{id}$

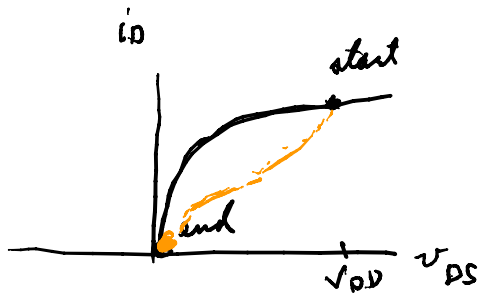
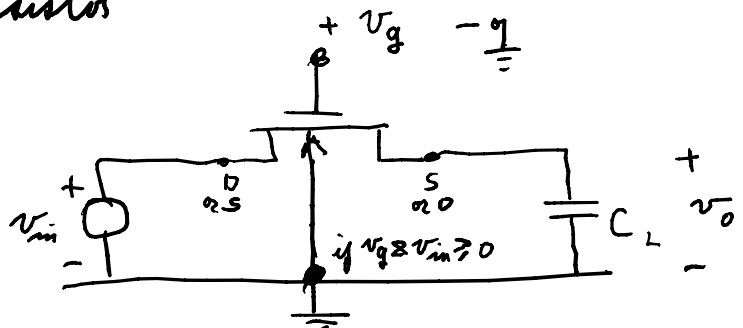
Connect output to input

$$i = f(v) = -g_m v$$

this is a negative resistor, resistance = $-\frac{1}{g_m}$

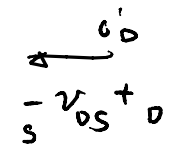


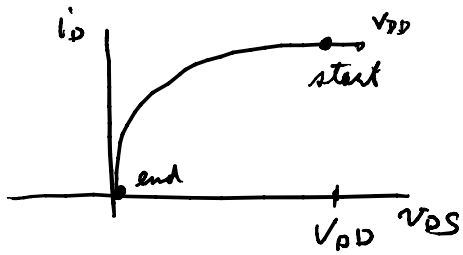
Pass transistor



case $v_o = "1" = V_{DD}$
 $v_g = "1" = V_{DD}$
 $v_{in} = "0" = \text{ground} = 0$

transitions from 1 to 0 at output





case $v_D = "0" = 0$ $\rightarrow i_D$
 $v_{in} = "1" = V_{DD}$ $\begin{matrix} + \\ P \end{matrix} v_{DS} \begin{matrix} - \\ S \end{matrix}$
 $v_G = "1" = V_{DD}$

transitions from 0 to 1 at output

the pass transistor acts as a switch

current for $v_g = 0$

